## NSN 5961-01-075-6833

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-075-6833 **Inclosure Material:** Plastic **Overall Length:** Between 0.560 inches and 0.625 inches **Overall Height:** Between 0.140 inches and 0.190 inches Overall Width: Between 0.380 inches and 0.420 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To.220 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 repetitive peak reverse voltage and 50.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 8.00 amperes forward current, total rms horsepower metric and 5.10 amperes forward current, total rms universal **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0